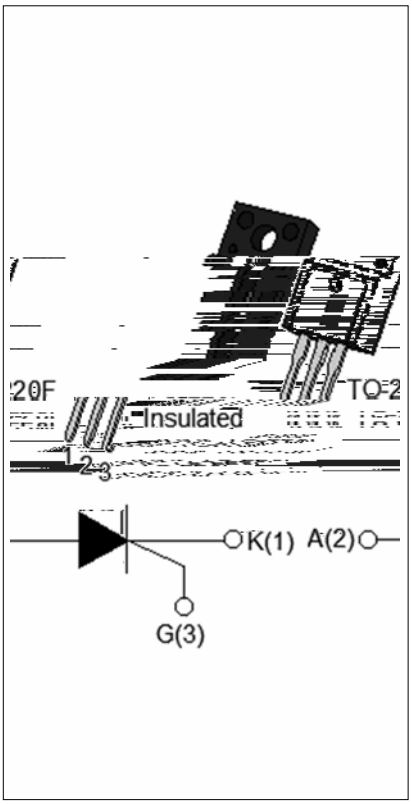
JCT640F 40A SCR

Rev.A.1.1

With high ability to withstand the shock loading of large current, JCT640F SCR provides high dV/dt rate with strong resistance to electromagnetic interference.It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three terminals to external heatsink,JCT640F provides a rated insulation voltage of 2000 V_{RMS}, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.



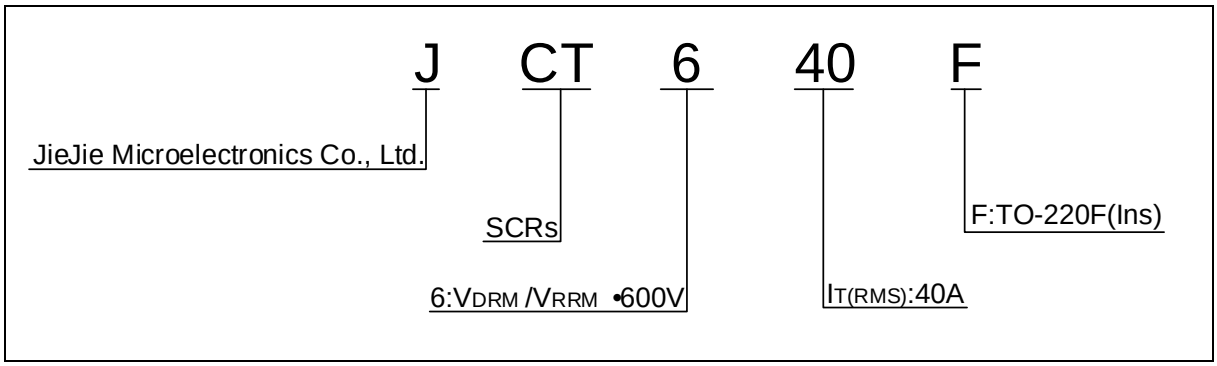
Symbol	Value	Unit
$I_{T(RMS)}$	40	A
V_{DRM}/V_{RRM}	600	V
I_{GT}	≤35	mA

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	600	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	600	V
Average on-state current (T_C ≤ 56)	$I_{T(AV)}$	25	A
RMS on-state current (T_C ≤ 56)	$I_{T(RMS)}$	40	A
Non repetitive surge peak on-state current (t_p=10ms, T_j=25)	I_{TSM}	500	A
Non repetitive surge peak on-state current (t_p=8.3ms, T_j=25)		540	
I^2t value for fusing (t_p=10ms , T_j=25)	I^2t	1250	A^2s
Critical rate of rise of on-state current (I_G=2 × I_{GT}, f=100Hz , T_j=125)	dI/dt	150	A/μs

Peak gate current (t_p=20μs , T_j=125)	I_{GM}	10	A
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

=25 unless otherwise specified)

	Value			Unit
n	MIN.	TYP.	MAX.	


J
CT
6
40
F
JieJie Microelectronics Co., Ltd.
SCRs
6:VDRM /VRRM •600V
IT(RMS):40A
F:TO-220F(Ins)

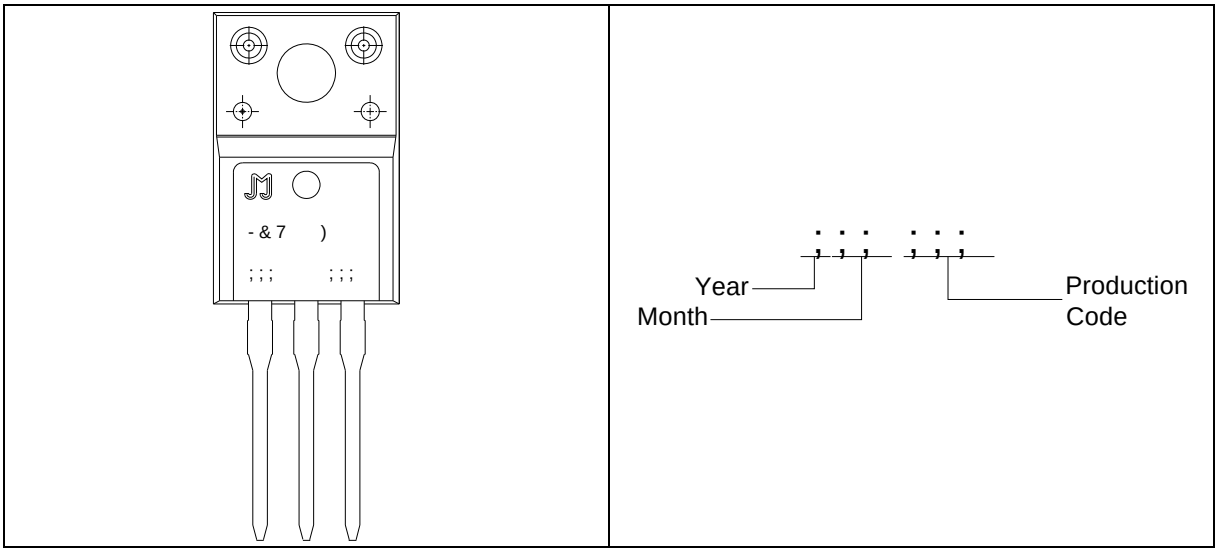

Year
Month
Production
Code

FIG.1: Maximum power dissipation versus RMS on-state current

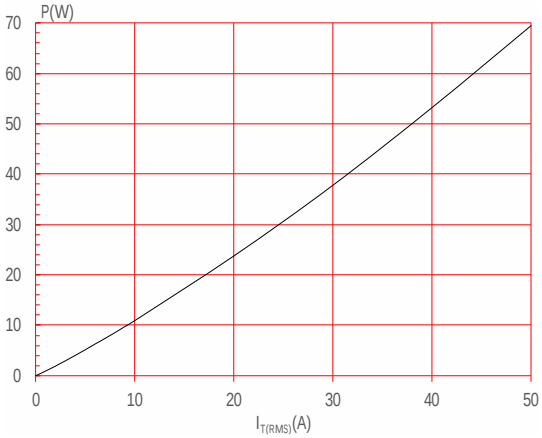


FIG.2: RMS on-state current versus case temperature

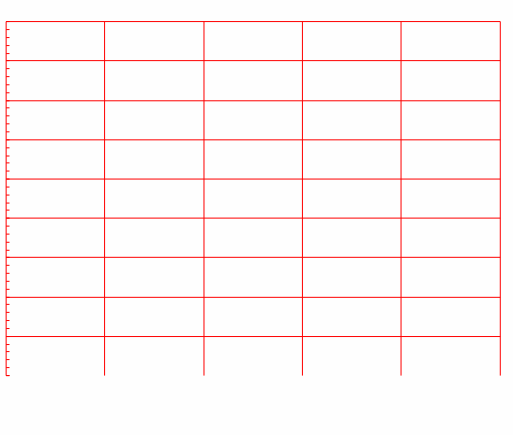
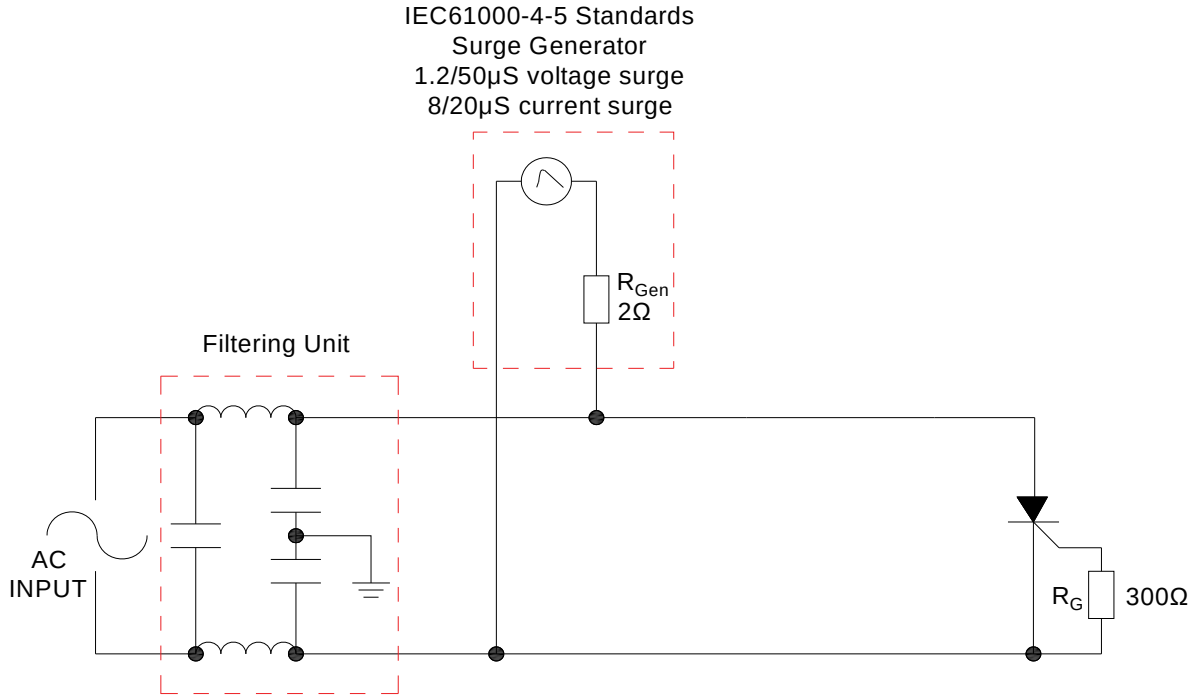


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics.

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT640F	600	35	TO-220F(Ins)	50	Tube

Document Revision History

Date	Revision	Changes
Apr.13, 2023	A.1.0	Last update
Sept.29, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA



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